



### **Applications**

- Video signal distribution in HFC and FTTx nodes
- Signal distribution in L-band and wireless remoting links
- High linearity, low power fiber links

#### **Features**

- Linear DFB laser design
- Output power up to 10 dBm available
- Bandwidth > 4000 MHz
- Optical Isolator
- Low power consumption
- Monitor photodiode
- RoHS

# Model 1933F/R/W Coaxial DFB Laser Diode

## 1310nm, Wide Bandwidth 5MHz – 4000MHz

Emcore's Model 1933 DFB lasers offer a low cost solution for linear fiberoptic links. These components can be cooled with external thermo-electric coolers for high stability, or run without TEC's to reduce power consumption. The DFB laser builds upon Ortel's long history of high performance, leading edge designs in CATV, wireless, and high speed digital applications. The laser diode devices are packaged in a compact hermetic assembly together with monitor photodiode and isolator, for flexible integration into various transmitter configurations.

### **Performance Highlights**

|  | Min  | Typical | Max  | Units |
|--|------|---------|------|-------|
| Operating Case Temperature Range         | -40  | -       | 85   | °C    |
|  | 3    | -       | 5.9  |       |
| Optical Output Power (1)                 | 6    | -       | 8.9  | dDm   |
| Optical Output Power                     | 9    | -       | 9.9  | dBm   |
|  | 10   | -       | 11.9 |       |
| Frequency Range                          | 5    | -       | 4000 | MHz   |
| Carrier-to-Noise Ratio (79 channels) (1) | 51   | -       | -    | dB    |
| Composite Second Order (79 channels) (1) |      |         |      |       |
| Standard Linearity                       | -    | -       | -57  | dBc   |
| Enhanced Linearity                       | -    | -       | -60  |       |
| Composite Triple Beat (79 channels) (1)  |      |         |      |       |
| Standard Linearity                       | -    | -       | -65  | dBc   |
| Enhanced Linearity                       | -    | -       | -68  |       |
| Center Wavelength                        | 1300 | -       | 1320 | nm    |
| Optical Return Loss (1)                  | 35   | -       | -    | dB    |
| Side Mode Suppression Ratio, CW (1)      | 30   | -       | -    | dB    |

<sup>(1)</sup> Performance at Tcase = 25 °C

See following pages for complete specifications and conditions.



## **Absolute Maximum Ratings**<sup>1</sup>

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

| Parameters                      | Symbol           | Condition/Notes  | MIN  | MAX    | Unit   |
|---------------------------------|------------------|------------------|------|--------|--------|
| Storage Temperature             | T <sub>STG</sub> | Non-Operating    | -40  | 85     | °C     |
| Operating Case Temperature      | T <sub>OP</sub>  | Continuous       | -40  | 85     | °C     |
| Laser Diode Forward Current     | I <sub>OP</sub>  | CW               | -    | 150    | mA     |
| Laser Diode Reverse Voltage     | $V_R$            | Continuous       | -    | 1.0    | V      |
| Photodiode Forward Current      | I <sub>MPD</sub> | Continuous       | -    | 2      | mA     |
| Photodiode Reverse Voltage      | $V_{MPD,R}$      | Continuous       | -    | 10     | V      |
| Average RF Input Power          | PIN              | 60 Seconds       | -    | 62     | dBmV   |
| Lead Soldering Temperature/Time | -                | -                | -    | 260/10 | °C/sec |
| Relative Humidity               | RH               | Continuous       | -    | 85     | %      |
| ESD                             | -                | Human Body Model | -500 | +500   | V      |

Absolute maximum data are limited to system design only; proper device performance is not guaranteed over rating listed above. Operation beyond these maximum conditions may degrade device performance, lead to device failure, shorter lifetime, and will invalidate the device warranty.

### **Electrical/Optical Characteristics**

| Parameters   | Symbol                 | Conditions/Notes   | Min     | Тур     | Max         | Unit  |
|--|------------------------|--|---------|---------|-------------|-------|
| Optical Output Power                                     |                        | 1933R opt model: 3 – 6dBm  | 3<br>5  | -       | 4.9<br>5.9  |       |
|  | Po                     | 1933W opt model: 3 – 10dBm   | 6       | -       | 8.9         | dBm   |
|  |                        | 1933F opt model: 3 – 10dBm   | 9<br>10 | -<br>-  | 9.9<br>11.9 |       |
| Threshold Current  | I <sub>TH</sub>        | $T_{case} = 25$ °C<br>$T_{case} = 45$ °C                           | -       | 8<br>13 | 15<br>20    | mA    |
| Laser Bias Current                                       | I <sub>OP</sub>        |  | -       | -       | 80          | mA    |
| Forward Voltage  | $V_{F}$                | I <sub>op</sub>  | -       | 1.17    | 1.8         | V     |
| Slope Efficiency   | SE                     | $T_{case} = 25^{\circ}C, I_{op}$                                   | 0.07    | -       | 0.3         | mW/mA |
| Thermal Slope Efficiency                                 | TSE                    | SE(Tc)/SE(25°C)<br>T <sub>case</sub> = -20°C to 85°C               | 0.4     | -       | 1.2         | -     |
| Laser Input Impedance                                    | Z                      | -  | 2       | 4       | 8           | Ω     |
| MPD Current  | I <sub>MPD</sub>       | $V_{MPD} = 5V, I_{op}$   | 200     | -       | 2000        | μΑ    |
| MPD Dark Current   | I <sub>D</sub>         | $V_{MPD} = 5V$ , $I_{op} = 0$<br>$T_{case} = 25^{\circ}C$          | -       | -       | 50          | nA    |
| Center Wavelength  | $\lambda_{\mathrm{c}}$ | I <sub>op</sub>  | 1300    | -       | 1320        | nm    |
| Relative Intensity Noise                                 | RIN                    | CW, I <sub>op</sub> , T <sub>case</sub> = 25°C<br>5 MHz - 1002 MHz | -       | -       | -150        | dB/Hz |
| Tracking Error   | ΔPf                    | $I_{MON} = const$<br>ER = $10log(P_O/2.0)$ [dB]                    | -1      | -       | +1          | dB    |
| Optical Isolation, T <sub>case</sub> = 25 <sup>o</sup> C | ISO                    | Double Isolator  | 45      | -       | -           | dB    |
| Spectral Width (-20 dB)                                  | Δλ                     | I <sub>op</sub>  | -       | 0.1     | 1.0         | nm    |
| Side Mode Suppression Ratio                              | SMSR                   | I <sub>op</sub>  | 30      | 45      | -           | dB    |
| Optical Return Loss                                      | ORL                    | $T_{case} = 25^{\circ}C$   | 35      | -       | -           | dB    |

<sup>1.</sup> Referenced to base of TO header.

### **Forward Path RF Characteristics**

| 1933F Performance Parameter   | Symbol          | Conditions/Notes                  | Min | Тур | Max        | Unit              |
|---|-----------------|-----------------------------------|-----|-----|------------|-------------------|
| Frequency Response Flatness 1   | S <sub>21</sub> | 5 MHz - 1002 MHz                  | -   | -   | 1          | dB <sub>p-p</sub> |
| Response Up-tilt <sup>1</sup>   |                 | 5 MHz - 1002 MHz                  | -1  |     | 3          | dB                |
| Carrier-to-Noise Ratio 2,3,4  | CNR             | l <sub>op</sub>                   | 51  | -   | -          | dB                |
| Composite Second Order <sup>2,3,4</sup> Standard Linearity Enhanced Linearity |                 | $I_{op}$ $T_{case} = 25^{\circ}C$ |     |     | -57<br>-60 | dBc               |
| Composite Triple Beat <sup>2,3,4</sup> Standard Linearity Enhanced Linearity  |                 | $I_{op}$ $T_{case} = 25^{\circ}C$ | -   | -   | -65<br>-68 | dBc               |

- 1.  $I_{op}$ ,  $T_{case}$  = 25°C. Test with the laser Input pin matched to a 50 $\Omega$  system.
- 2. 3.7% OMI, 79 NTSC unmodulated carriers (50 MHz to 550 MHz). 10 km fiber.
- 3. Received power = 0 dBm.
- 4.  $I_{op}$ ,  $T_{case} = 25$ °C. Test with the laser Input pin matched to a 75 $\Omega$  system.

#### **Return Path RF Characteristics**

| 1933R Performance Parameters   | Symbol          | Conditions/Notes   | Min    | Тур | Max        | Unit              |
|--|-----------------|--|--------|-----|------------|-------------------|
| Frequency Response Flatness 1  | S <sub>21</sub> | 5 MHz - 200 MHz  | -      | -   | 1          | dB <sub>p-p</sub> |
| Second Order Distortion <sup>2</sup> Standard Linearity Enhanced Linearity |                 | $P_F = 3$ dBm, OMI = 10% each<br>2-tone test: f1=7MHz, f2=56MHz<br>20 km of fiber<br>(7.5 dB total loss with connector)<br>f1 + f2         | -<br>- | -   | -52<br>-58 | dBc               |
| Third Order Distortion <sup>2</sup> Standard Linearity Enhanced Linearity  |                 | P <sub>F</sub> = 3 dBm, OMI = 10% each<br>2-tone test: f1=7MHz, f2=56MHz<br>20 km of fiber<br>(7.5 dB total loss with connector)<br>2f2-f1 | -<br>- | -   | -63<br>-65 | dBc               |

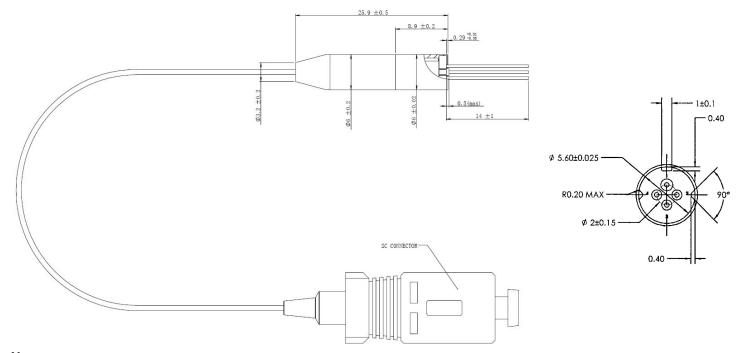
- 1.  $I_{op}$ ,  $T_{case} = 25$ °C. Test with the laser Input pin matched to a  $50\Omega$  system.
- 2.  $I_{op}$ ,  $T_{case} = 25$ °C. Test with laser input pin matched to a 75 $\Omega$  system.

#### **Wide Bandwidth Path RF Characteristics**

| 1933W Performance Parameters                              | Symbol          | Conditions/Notes                                 | Min  | Тур | Max | Unit              |
|---|-----------------|--|------|-----|-----|-------------------|
| Frequency Response Flatness 1                             | S <sub>21</sub> | 900 MHz – 4000 MHz                               | -    | -   | 4   | dB <sub>p-p</sub> |
| Input Third Order Intercept <sup>2</sup>                  | IIP3            | Standard Linearity, Ibb                          | 30   | -   | -   | dBm               |
| 1dB Compression Point <sup>3</sup>                        | $P_{1dB}$       | I <sub>bb</sub>                                  | 16   | -   | -   | dBm               |
| Relative Intensity Noise <sup>4</sup> (BW = 50MHz – 2GHz) | RIN             | Tc = 25℃, lop<br>Constant opt power              | -150 | -   | -   | dB/Hz             |
|   | HIIN            | Tc = -20 °C to +85 °C, lop<br>Constant opt power | -145 | -   | -   | dB/Hz             |

- 1.  $I_{op}$ ,  $T_{case} = 25$ °C. Test with the laser Input pin matched to a 50 $\Omega$  system.
- 2. IIP3 is measured at I<sub>bb</sub> where I<sub>bb</sub> is the bias point at which simultaneously the laser at its best linearity and the optical power is within specification. Test Frequency F1 = 2700MHz, F2 = 2703MHz, RF in = 0dBm/frequency. 0km fiber.
- 3. Test at 2700MHz. 0km fiber.
- 4. Guaranteed by design. Not to be tested in production

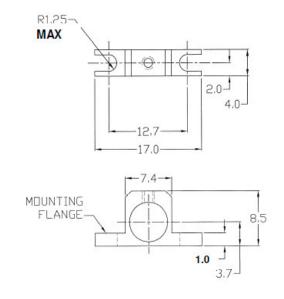
# **Package Outline Drawing**



### Note:

Dimensions are in mm

## **Mounting Bracket**



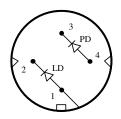
#### NOTES:

- 1. UNIT: mm
- 2. TOLERANCE: ±0.1mm UNLESS OTHERWISE SPECIFIED

## Reliability/Quality

Designed to meet qualification requirements of Telcordia<sup>TM</sup> (Bellcore) GR-468-CORE.

### **Schematic and Pinout A**

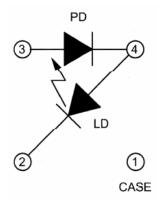


Pinout A
Bottom View

### **Pin Definitions for Pinout A**

| Pin | Description           |  |  |  |  |  |
|-----|-----------------------|--|--|--|--|--|
| 1   | LD Anode, Case Ground |  |  |  |  |  |
| 2   | LD Cathode            |  |  |  |  |  |
| 3   | PD Cathode            |  |  |  |  |  |
| 4   | PD Anode              |  |  |  |  |  |

### **SCHEMATIC AND PINOUT C**



**Bottom View** 

### PIN DEFINITIONS FOR PINOUT C

| Pin | Description          |  |  |  |  |
|-----|----------------------|--|--|--|--|
| 1   | Case                 |  |  |  |  |
| 2   | LD Cathode           |  |  |  |  |
| 3   | PD Anode             |  |  |  |  |
| 4   | LD Anode, PD Cathode |  |  |  |  |

### **Laser Safety**

This product meets the appropriate standard in Title 21 of the Code of Federal Regulations (CFR). FDA/CDRH Class 1 laser product. This device has been classified with the FDA/CDRH under accession number 0220191.

All Versions of this laser are Class 1 laser product, tested according to IEC 60825-1:2007/EN 60825-1:2007

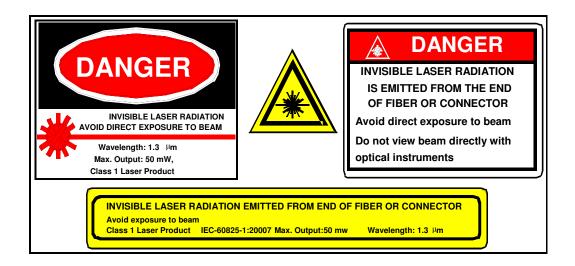
Wavelength =  $1.3 \mu m$ .

Maximum power = 50 mW.

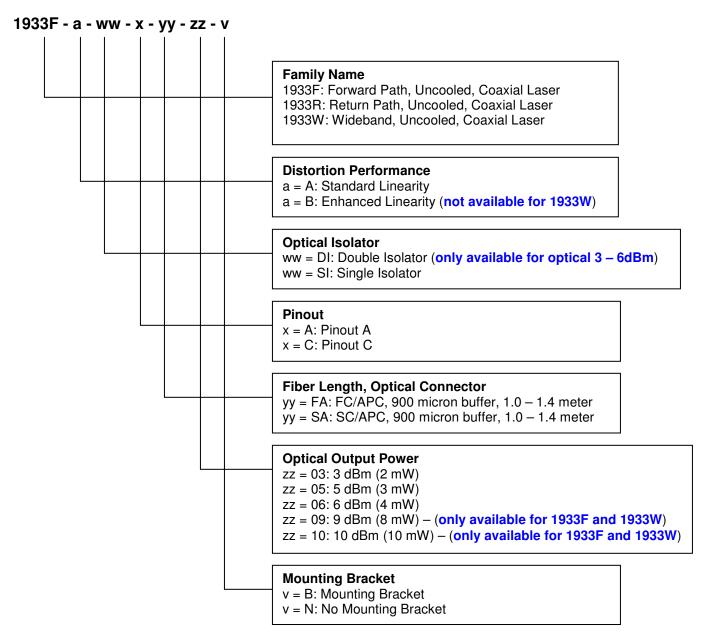
Because of size constraints, laser safety labeling (including an FDA class 1 label) is not affixed to the module, but attached to the outside of the shipping carton.

Product is not shipped with power supply.

Caution: Use of controls, adjustments and procedures other than those specified herein may result in hazardous laser radiation exposure.



### **Ordering Code Definitions**



#### Example

**1933F-B-DI-A-SA-10-N**: Forward Path Uncooled Coaxial Laser, Enhanced Linearity, Double Isolator, Pinout A, SC/APC optical connector, 10dBm optical power, No Mounting Bracket.

Information contained herein is deemed to be reliable and accurate as of issue date. EMCORE reserves the right to change the design or specifications of the product at any time without notice. EMCORE and the EMCORE logo are trademarks of EMCORE Corporation.

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